

	Phototransistor Output: GaAs AC Input									
	Part Number	CTR @ ± 10 mA I_F (%)		BV_{CEO} (V)	BV_{CBO} (V)	$V_{CE(sat)}$ (V)	t_{ON}/t_{OFF} (μ s)	V_{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
		min	max	min	min	max	max			
H11AA1	20	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U	
H11AA1.300	20	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V	
H11AA2	10	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U	
H11AA2.300	10	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V	
H11AA3	50	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U	
H11AA3.300	50	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V	
H11AA4	100	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U	
H11AA4.300	100	—	30	70	0.4	—	5.3 kV	E	A, B, D, F, N, S, U, V	

	Phototransistor Output: GaAs AC Input (No base connection) (4-Pin)									
	Part Number	CTR @ ± 1 mA I_F (%)		BV_{CEO} (V)	BV_{CBO} (V)	$V_{CE(sat)}$ (V)	t_{ON}/t_{OFF} (μ s)	V_{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
		min	max	min	min	max	max			
H11AA814	20	300	35	6	0.2	18	5.3 kV	G	A, U	
H11AA814.300	20	300	35	6	0.2	18	5.3 kV	G	A, U, V	
H11AA814A	50	150	35	6	0.2	18	5.3 kV	G	A, U	
H11AA814A.300	50	150	35	6	0.2	18	5.3 kV	G	A, U, V	

	Logic Output: GaAs AC Input									
	Part Number	$I_{I(ON)}$ RMS (mA)	$I_{I(OFF)}$ RMS (mA)	V_{CC} (V)	$V_I(ON)$ RMS (V)	$V_I(OFF)$ RMS (V)	I_{OH} (μ A)	V_{ISO} AC[RMS]	Pkg dwg	Agency Approvals (see pg 23)
		min	max	max	min	max	max			
MID400	4	0.15	7	90	5.5	100	2.25 kV	D	A, U	

Notes

A complete list of agencies appears on page 23.
 Optocoupler Package outlines appear on pages 24, 25, and 26.